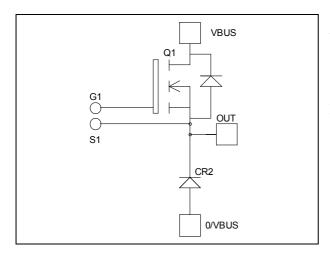
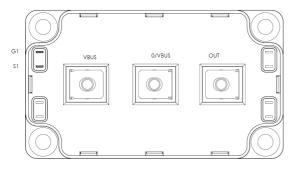


Buck chopper **MOSFET Power Module**

 $V_{DSS} = 100V$ $I_D = 495A$ @ Tc = 25°C





Application

- AC and DC motor control
- Switched Mode Power Supplies

Features

- Power MOS V® MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- **RoHS Compliant**

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit	
$V_{ m DSS}$	Drain - Source Breakdown Voltage		100	V
I_D	Continuous Drain Current	$T_c = 25^{\circ}C$	495	
1D	Continuous Diani Current	$T_c = 80$ °C	370	A
I_{DM}	Pulsed Drain current	1900		
V_{GS}	Gate - Source Voltage	±30	V	
R _{DSon}	Drain - Source ON Resistance		2.5	mΩ
P_{D}	Maximum Power Dissipation	$T_c = 25^{\circ}C$	1250	W
I_{AR}	Avalanche current (repetitive and non repetitive)		100	A
E_{AR}	Repetitive Avalanche Energy		50	mJ
E_{AS}	Single Pulse Avalanche Energy	Energy		1113

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit	
т	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 100V$	$T_j = 25^{\circ}C$			400	4	
$I_{ m DSS}$		$V_{GS} = 0V, V_{DS} = 80V$	$T_j = 125$ °C			2000	μΑ	
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 200A$			2.25	2.5	mΩ	
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 10$ mA		2		4	V	
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±400	nA	

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		40		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		15.7		nF
C_{rss}	Reverse Transfer Capacitance	f=1MHz		5.9		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		1360		
Q_{gs}	Gate – Source Charge	$V_{\rm Bus} = 50 V$		240		nC
Q_{gd}	Gate – Drain Charge	$I_D = 400A$		720		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C		160		
T_{r}	Rise Time	$V_{GS} = 15V$ $V_{Bus} = 66V$		240		ma
$T_{d(off)}$	Turn-off Delay Time	$I_{\rm D} = 400 A$		500		ns
T_{f}	Fall Time	$R_G = 1.25\Omega$		160		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		2.2		m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.41		mJ
E_{on}	Turn-on Switching Energy	Inductive switching @ 125°C		2.43		m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 66V$ $I_D = 400A, R_G = 1.25\Omega$		2.56		mJ

Chopper diode ratings and characteristics

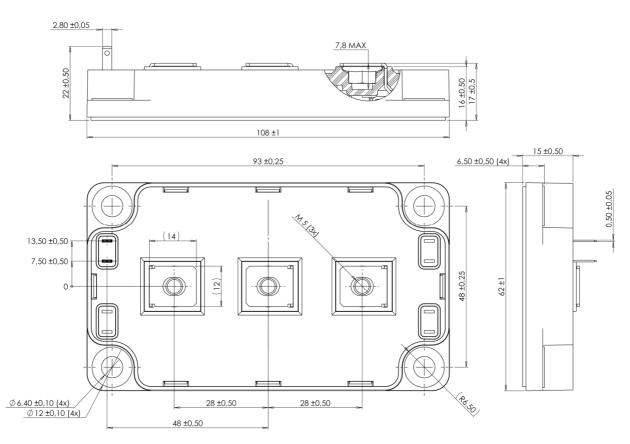
Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			200			V
I_{RM}	Maximum Reverse Leakage Current	V _R =200V	$T_j = 25^{\circ}C$			750	Δ
1 _{RM}			$T_{j} = 125^{\circ}C$			1000	μA
I_{F}	DC Forward Current		$Tc = 80^{\circ}C$		400		A
	Diode Forward Voltage	$I_F = 400A$			1		V
V_{F}		$I_F = 800A$			1.4		
		$I_F = 400A$	$T_i = 125$ °C		0.9		
t_{rr}	Reverse Recovery Time	$ \begin{array}{c c} I_F = 400A & T_j = 25^{\circ}C \\ V_R = 133V & T_j = 125^{\circ}C \\ di/dt = 800A/\mu s & T_j = 25^{\circ}C \\ \hline T_j = 125^{\circ}C & \\ \hline T_j = 125^{\circ}C & \\ \hline \end{array} $	$T_j = 25^{\circ}C$		60		ns
·rr			$T_{j} = 125^{\circ}C$		110		113
Q _{rr}	Reverse Recovery Charge		$T_j = 25$ °C		800		nC
				3360		IIC	



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit	
R_{thJC}	Junction to Case Thermal Resistance		Transistor			0.1	°C/W	
IX _{th} JC			Diode			0.14	C/ W	
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V	
T_{J}	Operating junction temperature range			-40		150		
T_{STG}	Storage Temperature Range					125	°C	
$T_{\rm C}$	Operating Case Temperature			-40		100		
Torque	Mounting torque	To heatsink	M6	3		5	N.m	
		For terminals	s M5	2		3.5	11.111	
Wt	Package Weight					300	g	

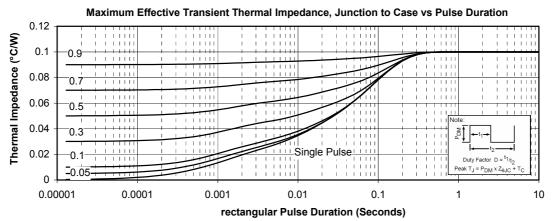
SP6 Package outline (dimensions in mm)

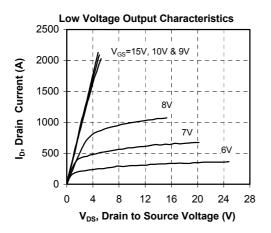


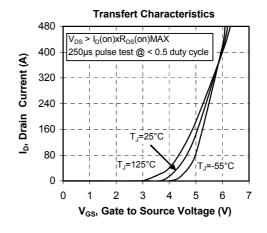
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

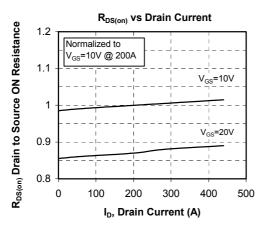


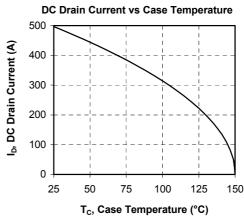
Typical Performance Curve



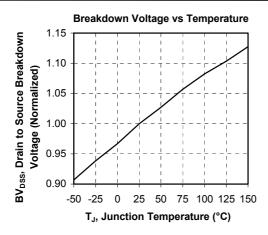


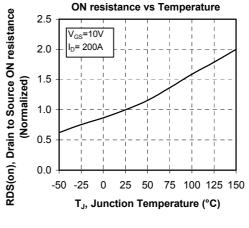


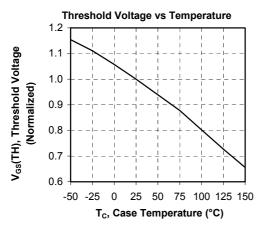


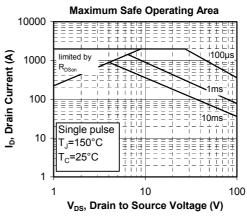


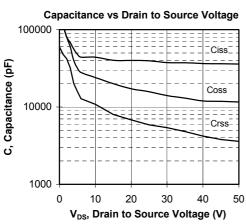


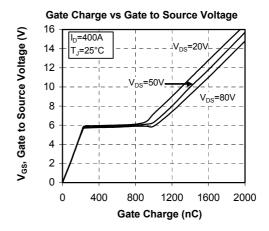




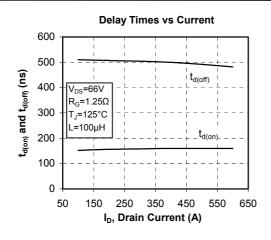


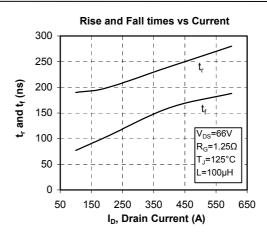


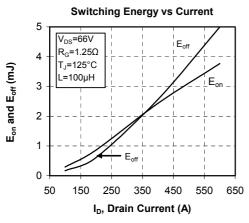


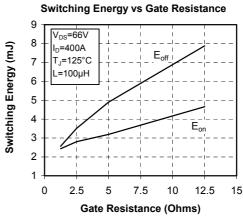


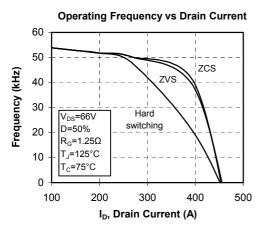


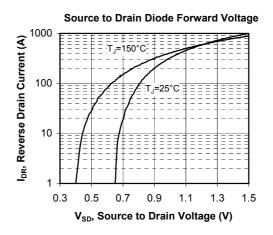














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